

PN2907A / MMBT2907A / PZT2907A **60 V PNP General Purpose Transistor**

Features

- High DC Current Gain (hFE) Range: 100 300
- · High-Current Gain Bandwidth Product (fT): 200 MHz (min.)
- Maximum Turn-On Time (ton): 45 ns
- Maximum Turn-Off Time (t_{off}): 100 ns
- Ultra-Small Surface-Mount Package: SOT-223 (PZT2907A)

Features

- · General-Purpose Amplifier
- Switch

Description

The PN2907A, MMBT2907A, and PZT2907A are 60 V -PNP bipolar transistors designed for use as a general-purpose amplifier or switch in applications that require up to 500 mA. Offered in an ultra-small surface-mount package (SOT-223), the PZT2907A is ideal for space-constrained systems. The NPN complementary types are the PN2222A, MMBT2222A, and PZT2222A; respectively.



Ordering Information

Part Number	Top Mark	Package	Packing Method	
PN2907ABU	2907A	TO-92 3 L	Bulk	
PN2907ATF	2907A	TO-92 3 L	Tape and Reel	
PN2907ATAR	2907A	TO-92 3 L	23L Ammo	
PN2907ATA	2907A	TO-92 3 L	Ammo	
PN2907ATFR	2907A	TO-92 3 L	Tape and Reel	
MMBT2907A_D87Z	2F	SOT-23 3L	Tape and Reel	
MMBT2907A	1MBT2907A 2F SOT-23 3L Ta		Tape and Reel	
PZT2907A	PZT2907A 2907A		Tape and Reel	

June 2013

Absolute Maximum Ratings⁽¹⁾

Stresses exceeding the absolute maximum ratings may damage the device. The device may not function or be operable above the recommended operating conditions and stressing the parts to these levels is not recommended. In addition, extended exposure to stresses above the recommended operating conditions may affect device reliability. The absolute maximum ratings are stress ratings only. Values are at $T_A = 25^{\circ}$ C unless otherwise noted.

Symbol	Parameter	Ratings	Units
V _{CEO}	Collector-Emitter Voltage	60	V
V _{CBO}	Collector-Base Voltage	60	V
V _{EBO}	Emitter-Base Voltage	5.0	V
Ι _C	Collector Current-Continuous	800	mA
T _J , T _{STG} ⁽³⁾	Operating and Storage Junction Temperature Range	-55 to + 150	°C

Note:

- 1. These ratings are limiting values above which the serviceability of any semiconductor device may be impaired. These ratings are based on a maximum junction temperature of 150 °C.
- 2. These are steady-state limits. Fairchild Semiconductor should be consulted on applications involving pulsed or low duty-cycle operations.
- 3. All voltages (V) and currents (A) are negative polarity for PNP Transistors.

Thermal Characteristics⁽²⁾

Values are at $T_A = 25^{\circ}C$ unless otherwise noted.

Symbol	Parameter	Max.			Units
Symbol	Falameter	PN2897A	MMBT2907A	PZT2907A	Units
р	Total Device Dissipation	625	350	1000	mW
PD	Derate above 25°C	5.0	2.8	8.0	mW/°C
$R_{\theta JC}$	Thermal Resistance, Junction to Case	83.3			°C/W
$R_{ hetaJA}$	Thermal Resistance, Junction to Ambient	200	357	125	°C/W

Note:

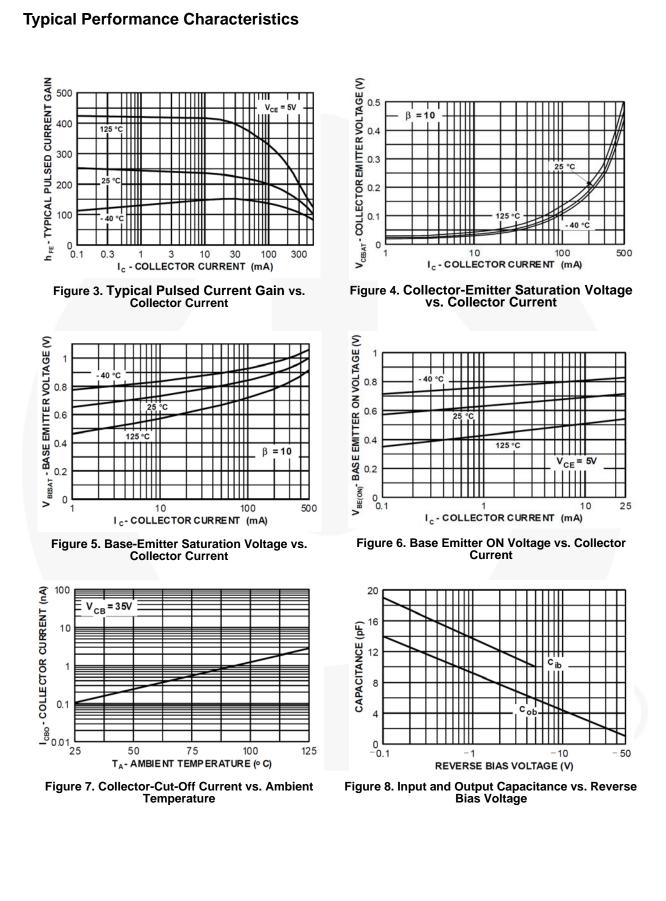
2. PCB size FR-4 76 x 114 x 0.6T mm³ (3.0 inch x 4.5 inch x 0.062 inch) with minimum land pattern size.

Symbol	Parameter	Test Condition	Min.	Max.	Units
Off Charao	teristics				
V _{(BR)CEO}	Collector-Emitter Breakdown Voltage ⁽⁴⁾	I _C = 1.0 mA, I _B = 0	60		V
V _{(BR)CBO}	Collector-Base Breakdown Voltage	I _C = 10 μA, I _E = 0	60		V
V _{(BR)EBO}	Emitter-Base Breakdown Voltage	I _E = 10 μA, I _C = 0	5.0		V
Ι _Β	Base Cut-Off Current	V _{CB} = 30 V, V _{EB} = 0.5 V		50	nA
I _{CEX}	Collector Cut-Off Current	V _{CE} = 30 V, V _{BE} = 0.5 V		50	nA
		V _{CE} = 50 V, I _E = 0		0.02	μA
I _{CBO}	Collector Cut-Off Current	V _{CB} = 50 V, I _E = 0, T _A =150°C		20	μA
On Charac	cteristics				
	DC Current Gain	I _C = 0.1 mA, V _{CE} = 10 V	75		
		I _C = 1.0 mA, V _{CE} = 10 V	100		1
I _{DSS}		I _C = 10 mA, V _{CE} = 10 V	100		1
		I _C = 150 mA, V _{CE} = 10 V ⁽⁴⁾	100	300	1
		$I_{\rm C}$ = 500 mA, $V_{\rm CE}$ = 10 V ⁽⁴⁾	50		
7	Collector-Emitter Saturation Voltage ⁽⁴⁾	I _C = 150 mA, V _{CE} = 15 V		0.4	V
I _{DSS}		I _C = 500 mA, V _{CE} = 50 V		1.6	V
1	Base-Emitter Saturation Voltage	$I_{\rm C}$ = 150 mA, $V_{\rm CE}$ = 15 V ⁽⁴⁾		1.3	V
I _{DSS}		I _C = 500 mA, V _{CE} = 50 V		2.6	V
Small Sigr	nal Characteristics				
f _T	Current Gain-Bandwidth Product	I _C = 50 mA, V _{CE} = 20 V, f = 100 MHz	200		MHz
C _{obo}	Output Capacitance	V _{CB} = 10 V, I _E = 0, f = 100 kHz		8.0	pF
C _{ibo}	Input Capacitance	V _{EB} = 2.0 V, I _C = 0, f = 100 kHz		30	pF
Switching	Characteristics				
t _{on}	Turn-on Time			45	
t _d	Delay	$-V_{CC} = 32 \text{ V}, \text{ I}_{C} = 150 \text{ mA},$ $-I_{B1} = 15 \text{ mA}$		10	
t _r	Rise Time			40	ne
t _{off}	Turn-off Time			100	– ns –
t _s	Storage Time	$V_{CC} = 6.0 \text{ V}, I_{C} = 150 \text{ mA},$ $I_{B1} = I_{B2} = 15\text{mA}$		80	
t _f	Fall Time			30	

Notes:

3. All voltages (V) and currents (A) are negative polarity for PNP transistors.

4. Pulse test: pulse width \leq 300 µs, duty cycle \leq 2.0%



Typical Performance Characteristics (Continued)

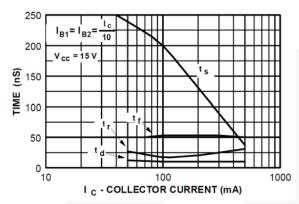


Figure 9. Switching Times vs. Collector Current

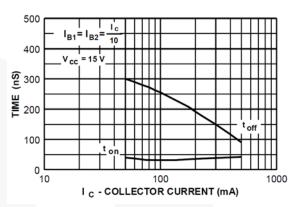


Figure 10. Turn-On and Turn-Off Times vs. Collector Current

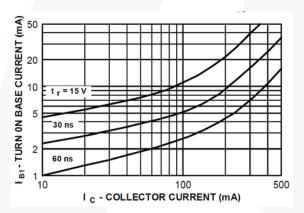


Figure 11. Rise Time vs. Collector and Turn-On Base Currents

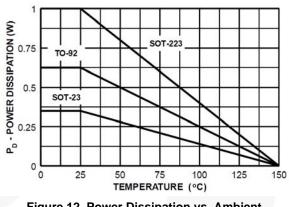
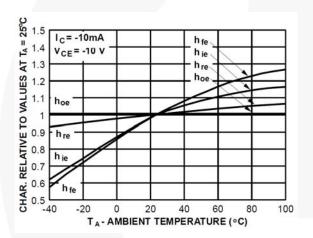


Figure 12. Power Dissipation vs. Ambient Temperature

CHAR. RELATIVE TO VALUES AT V_{CE} = -10V 1.3 1.2 hre and hoe hfe 1.1 h ie 1 h je 0.9 CE = -10 V TA = 25°C 0.8 -5 -10 -20 - 50 -2 -4 -8 -12 Ic-COLLECTOR CURRENT (mA) V_{CE}- COLLECTOR VOLTAGE (V) **Figure 13. Common Emitter Characteristics**



Typical Performance Characteristics (f = 1.0 kHz)

Figure 15. Common Emitter Characteristics

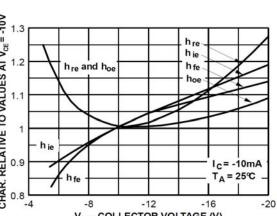


Figure 14. Common Emitter Characteristics

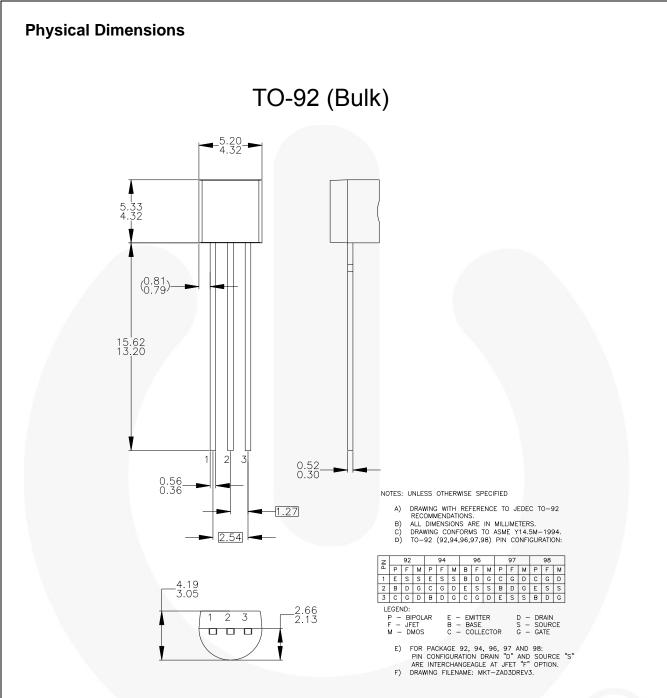


Figure 16. 3-LEAD, TO92, JEDEC TO-92 COMPLIANT STRAIGHT LEAD CONFIGURATION (OLD TO92AM3) (ACTIVE)

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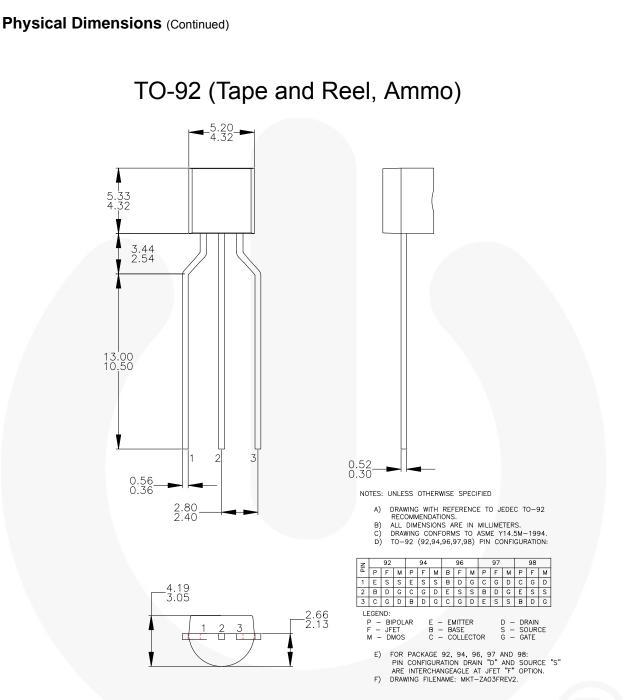


Figure 17. 3-LEAD, TO92, MILDED 0.200 IN LINE SPACING LD FORM (J61Z OPTION) (ACTIVE)

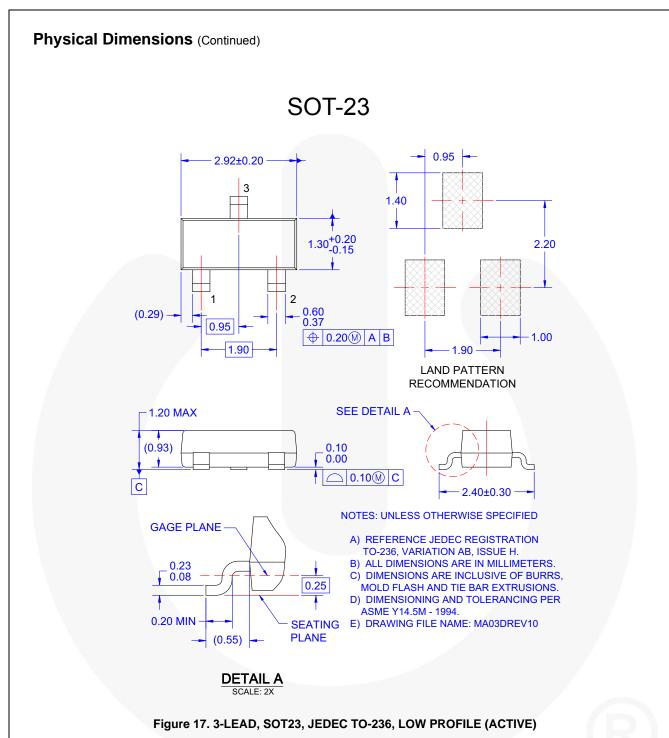
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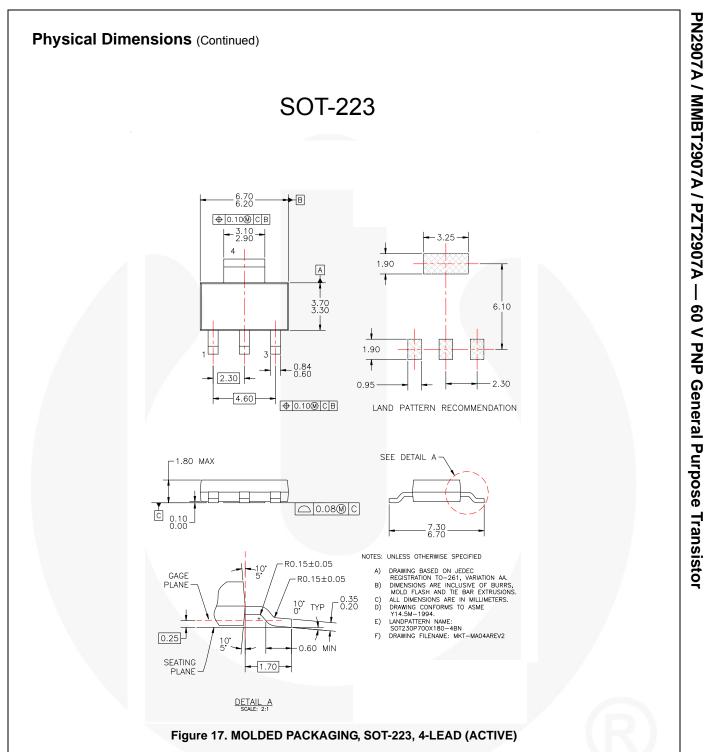
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Rev. 164